

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Yasuhiro OKAMOTO et al.
Title: FIELD-EFFECT TRANSISTOR HAVING GROUP III
NITRIDE ELECTRODE STRUCTURE
Appl. No.: 10/538,739
Filing Date: 11/9/2005
Examiner: Sarah Kate Salerno
Art Unit: 2814
Confirmation No.: 7288

AMENDMENT AND REPLY UNDER 37 C.F.R. 1.116

Mail Stop AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

This communication is responsive to the Final Office Action dated November 16, 2010, concerning the above-referenced patent application.

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this document.

Remarks/Arguments begin on page 6 of this document.

Please amend the application as follows: